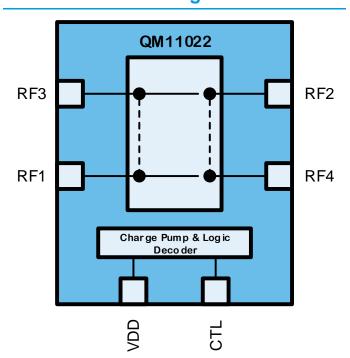


### **Product Description**

The QM11022 is a dual-pole double-throw transfer switch designed for general purpose switching applications where RF port transfer (port swapping) control is needed. The low insertion loss along with excellent linearity performance makes the QM11022 ideal for multi-mode GSM, EDGE, UMTS, and LTE handset applications. The RF ports can be directly connected in  $50\Omega$  systems and control logic is compatible with 1.3V to 2.7V systems. The supply voltage is intended for connection to 2.8V systems but the device is operable from 2.4V to 5.5V. The compact 1.1mm x 1.5mm size offers mobile handset designers an easy-to-use switch component for quick integration into multimode, multi-band systems.

### **Functional Block Diagram**





10 Pin 1.1 x 1.5 x 0.59 mm Package

#### **Feature Overview**

- Low Insertion Loss
- High Port-to-Port Isolation
- GPIO Interface for 1.3V to 2.7V Control Logic
- Broadband Performance Suitable for All Cellular Modulation Schemes up to 6GHz
- Very Low Current Consumption
- Linearity and Harmonic Performance Ideally Suited for LTE Applications
- DC blocking capacitors are not required in typical applications

### **Applications**

- Cellular Handset Applications
- Cellular Modems and USB Devices
- Multi-Mode GSM, EDGE, WCDMA, and LTE Applications

### **Ordering Information**

	PART NO.	DESCRIPTION
QM11022SB		5-pc Sample Bag
	QM11022SR	100-pc, 7" Reel
	QM11022TR13-5K	5000-pc, 13" Reel
	QM11022PCK	Fully Assembled EVB



# **Absolute Maximum Ratings**

PARAMETER	RATING
Storage Temperature	-65 to +150 °C
Operating Temperature	-30 to +90°C
V <sub>DD</sub>	6.0 V
C <sub>TL1</sub>	3.0 V
Maximum Input Power	
Momentary Infrequent Occurrence	39 dBm, 1:1 VSWR, +90°C, 25% DC
Continuous Operation	37.5 dBm, 1:1 VSWR, +25°C, 25% DC 36.5 dBm, 1:1 VSWR, +90°C, 25% DC

Operation of this device outside the parameter ranges given above may cause permanent damage.

# **Recommended Operating Conditions**

PARAMETER	MIN.	TYP.	MAX.	UNITS
V <sub>DD</sub> Supply Voltage	2.4	2.8	5.5	V
V <sub>DD</sub> Supply Current		57	80	μA
C <sub>TL</sub> Logic Low Voltage	0.00	0.00	0.45	V
C <sub>TL</sub> Logic High Voltage	1.3	1.8	2.7	V
C <sub>TL</sub> Logic High Current		0.1	5	μA
Turn-On Time (50%V <sub>DD</sub> to 90% RF)			20	μs
Switching Speed (IL Based, 10% to 90%)		1.8	3	μs

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.



# **Electrical Specifications**

Test conditions unless otherwise stated: all unused RF ports terminated in  $50\Omega$ , Input and Output =  $50\Omega$ , T =  $25^{\circ}$ C, V<sub>DD</sub> = 2.8V, Logic State = RF1-RF4; RF2-RF3 and RF1-RF3; RF2-RF4

PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Frequency Range		600		960	MHz
Insertion Loss					
RF1 to RF3	Logic State = RF1-RF3, RF2-RF4		0.27		dB
RF1 to RF4	Logic State = RF1-RF4, RF2-RF3		0.27		dB
RF2 to RF3	Logic State = RF1-RF4, RF2-RF3		0.28		dB
RF2 to RF4	Logic State = RF1-RF3, RF2-RF4		0.26		dB
Isolation					
RF1 to RF2, RF3 to RF4	Logic State = RF1-RF4, RF2-RF3		34		dB
RF1 to RF2, RF3 to RF4	Logic State = RF1-RF3, RF2-RF4		35		dB
Harmonics					
2 <sup>nd</sup> Harmonic			-90		dBm
3 <sup>nd</sup> Harmonic	Frequency = 824MHz to 915MHz; Pin = 26dBm; CW		-81		dBm
Up to 12.75GHz	Zoubin, Gw		-115		dBm
2 <sup>nd</sup> Harmonic (B13)	Frequency = 786.5MHz; Pin = 26dBm; CW		-87		dBm
2 <sup>nd</sup> Harmonic			-68		dBm
3 <sup>rd</sup> Harmonic	Frequency = 824MHz; Pin = 35dBm; CW		-53		dBm
IIP2	F1 = 26dBm; F2 = -20dBm				
Band 5 & 6	F1 = 836.5MHz; F2 = 1718MHz; Rx Freq = 881.5MHz		132		dBm
IIP3	F1 = 20dBm; F2 = -15dBm				
Band 5 & 6	F1 = 836.5MHz; F2 = 791.5MHz; Rx Freq = 881.5MHz		77		dBm
VSWR					
RF1, RF2, RF3, RF4	824MHz to 960MHz		1.06		:1



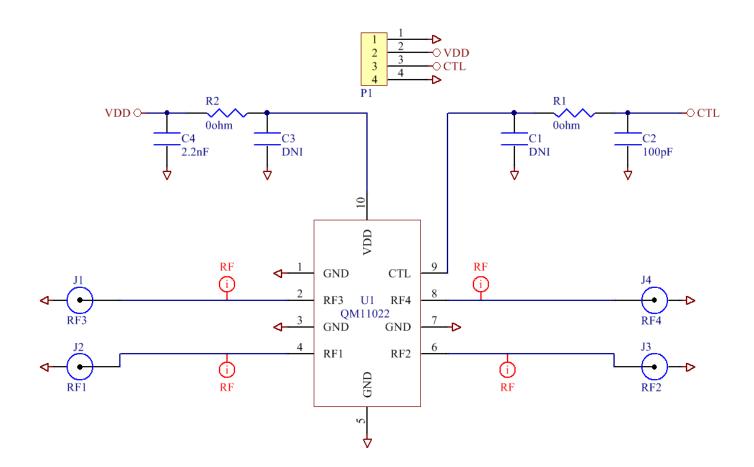
PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Frequency Range		1425		2200	MHz
Insertion Loss					
RF1 to RF3	Logic State = RF1-RF3, RF2-RF4		0.30		dB
RF1 to RF4	Logic State = RF1-RF4, RF2-RF3		0.31		dB
RF2 to RF3	Logic State = RF1-RF4, RF2-RF3		0.32		dB
RF2 to RF4	Logic State = RF1-RF3, RF2-RF4		0.30		dB
Isolation					
RF1 to RF2, RF3-RF4	Logic State = RF1-RF4, RF2-RF3		27		dB
RF1 to RF2, RF3-RF4	Logic State = RF1-RF3, RF2-RF4		27		dB
Harmonics					
2 <sup>nd</sup> Harmonic			-80		dBm
3 <sup>nd</sup> Harmonic	Frequency = 1710MHz to 1910MHz; P <sub>in</sub> =		-79		dBm
Up to 12.75GHz	26dBm; CW		-122		dBm
2 <sup>nd</sup> Harmonic			-69		dBm
3 <sup>nd</sup> Harmonic	Frequency = 1910MHz; P <sub>in</sub> = 33dBm; CW		-56		dBm
IIP2	F1 = 26dBm; F2 = -20dBm				
Band II (PCS)	F1 = 1880MHz; F2 = 3840MHz; Rx Freq = 1960MHz		127		dBm
IIP3	F1 = 20dBm; F2 = -15dBm				
Band 2 (PCS)	F1 = 1880MHz; F2 = 1800MHz; Rx Freq = 1960MHz		76		dBm
Band 1 (IMT)	F1 = 1950; F2 = 1760MHz; Rx Freq = 2140MHz		74		dBm
VSWR					
RF1, RF2, RF3, RF4	1427MHz to 2170MHz		1.1		:1
, -,					
Frequency Range		2300		2690	MHz
Insertion Loss					
RF1 to RF3	Logic State = RF1-RF3, RF2-RF4		0.33		dB
RF1 to RF4	Logic State = RF1-RF4, RF2-RF3		0.34		dB
RF2 to RF3	Logic State = RF1-RF4, RF2-RF3		0.36		dB
RF2 to RF4	Logic State = RF1-RF3, RF2-RF4		0.33		dB
Isolation					
RF1 to RF2, RF3-RF4	Logic State = RF1-RF4, RF2-RF3		25		dB
RF1 to RF2, RF3-RF4	Logic State = RF1-RF3, RF2-RF4		25		dB
Harmonics					
2 <sup>nd</sup> Harmonic	Frequency = 2500MHz to 2570MHz; P <sub>in</sub> =		-78		dBm
3 <sup>nd</sup> Harmonic	26dBm; CW		-76		dBm
IIP2	F1 = 20dBm; F2 = -15dBm		10		35111
Band 7	F1 = 2535MHz; F2 = 120MHz; Rx Freq = 2655MHz		128		dBm
IIP3	F1 = 20dBm; F2 = -15dBm				
Band 7	F1 = 2535MHz; F2 = 2415MHz; Rx Freq = 2655MHz		73		dBm
VSWR					
RF1, RF2, RF3, RF4	2300MHz to 2690MHz	1	1.1		:1



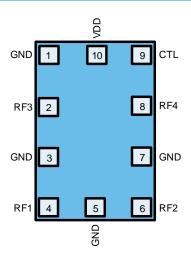
PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Frequency Range		3400		3800	MHz
Insertion Loss					
RF1 to RF3	Logic State = RF1-RF3, RF2-RF4		0.42		dB
RF1 to RF4	Logic State = RF1-RF4, RF2-RF3		0.41		dB
RF2 to RF3	Logic State = RF1-RF4, RF2-RF3		0.45		dB
RF2 to RF4	Logic State = RF1-RF3, RF2-RF4		0.39		dB
Isolation					
RF1 to RF2, RF3-RF4	Logic State = RF1-RF4, RF2-RF3		21		dB
RF1 to RF2, RF3-RF4	Logic State = RF1-RF3, RF2-RF4		21		dB
VSWR					
RF1, RF2, RF3, RF4	3400MHz to 3800MHz		1.2		:1
Frequency Range		5000		6000	MHz
Insertion Loss					
RF1 to RF3	Logic State = RF1-RF3, RF2-RF4		0.55		dB
RF1 to RF4	Logic State = RF1-RF4, RF2-RF3		0.51		dB
RF2 to RF3	Logic State = RF1-RF4, RF2-RF3		0.61		dB
RF2 to RF4	Logic State = RF1-RF3, RF2-RF4		0.55		dB
Isolation					
RF1 to RF2, RF3-RF4	Logic State = RF1-RF4, RF2-RF3		19		dB
RF1 to RF2, RF3-RF4	Logic State = RF1-RF3, RF2-RF4		18		dB
VSWR					
RF1, RF2, RF3, RF4	5000MHz to 6000MHz		1.3		:1



# **Application Circuit Schematic**



# **Pin Configuration and Description**



Top View

PIN NO.	LABEL	DESCRIPTION
_1	GND	Ground
2	RF3	RF Port connecting to either RF1 or RF2. Avoid applying DC voltage
3	GND	Ground
4	RF1	RF Port connecting to either RF3 or RF4. Avoid applying DC voltage
5	GND	Ground
6	RF2	RF Port connecting to either RF3 or RF4. Avoid applying DC voltage
7	GND	Ground
8	RF4	RF Port connecting to either RF1 or RF2. Avoid applying DC voltage
9	CTL	Logic Control pin
10	V <sub>DD</sub>	Power Supply pin

### **Control Logic**

The Switch is controlled by  $V_{\text{DD}}$  and  $C_{\text{TL}}$ .

LOGIC STATE	V <sub>DD</sub>	C <sub>TL</sub>	DESCRIPTION	
Off	0V	Low	Off or Standby – low current state	
RF1-RF3;RF2-RF4	"V <sub>DD</sub> "	Low	RF1 connected to RF3 and RF2 connected to RF4	
RF1-RF4;RF2-RF3	"V <sub>DD</sub> "	High	RF1 connected to RF4 and RF2 connected to RF3	

NOTE: The switch is in the Off or Standby state only when the V<sub>DD</sub> supply is low. The RF performance is undefined in the Off State

### **Power On and Off Sequence**

It is very important that the user adheres to the correct power-on/off sequence in order to avoid damaging the part. First apply  $V_{DD}$  before applying a high to  $C_{TL}$ .

#### Power On -

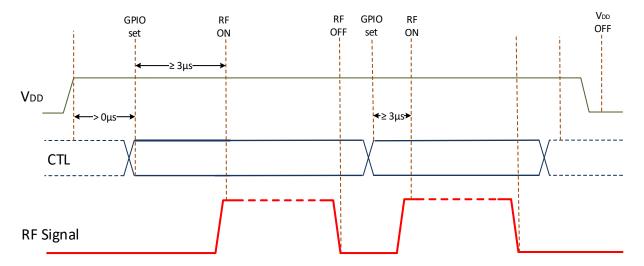
- 1. Apply voltage supply V<sub>DD</sub>
- 2. Apply Logic signal CTL
- 3. Wait 5µs or greater and then apply the RF signal

#### **Changing Switch Position**

- 1. Remove RF
- 2. Change control voltage CTL
- 3. Wait 5µs or greater and then apply the RF signal

#### Power Off -

- 1. Remove the RF signal
- 2. Remove the logic signal CTL
- 3. Remove the voltage supply V<sub>DD</sub>

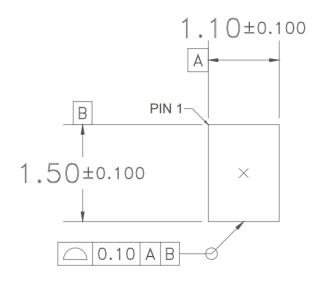


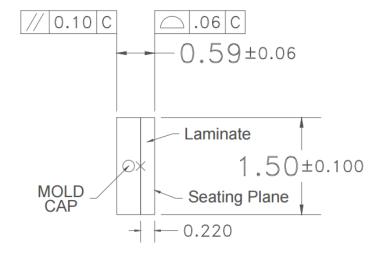




### **Mechanical Information**

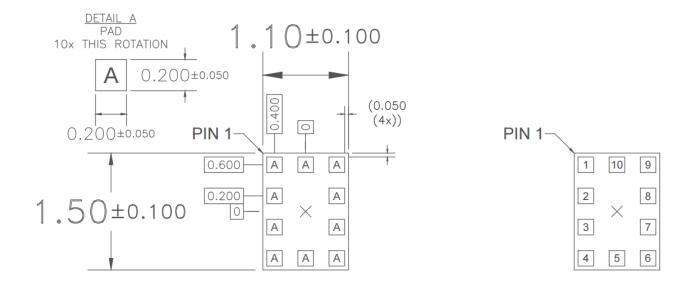
#### **Package Drawing**





Top View

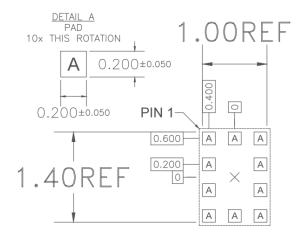
Side View



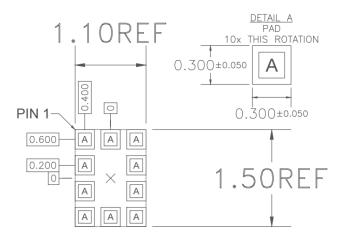
Top View xRay



#### **PCB Design Requirements**



Recommended Land Pattern



Recommended Land Pattern Mask

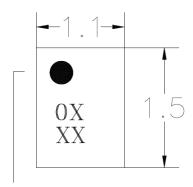
#### Notes:

- 1. All dimensions are in milimeters. Angles are in degrees.
- 2. Dimension and tolerance formats conform to ASME Y14.4M-1994.
- 3. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.





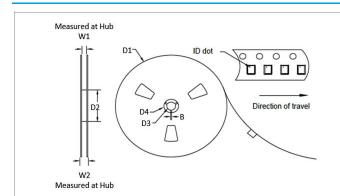
### **Branding Diagram**

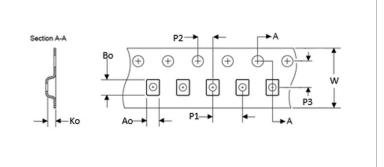


Pin 1 Indicator
0XXX
"0" is the one digit product code
"XXX" is the 3 digit Trace Code
assigned by sub-con

Unit: mm

# **Tape and Reel Information**





Measure	Symbol	Size (mm)
Diameter	D1	330.0
Thickness	W2	14.2
Space Between Flange	W1	8.8
Outer Diameter	D2	102.0
Arbor Hole Diameter	D3	13.0
Key Slit Width	В	2.0
Key Slit Diameter	D4	20.2
	Diameter Thickness Space Between Flange Outer Diameter Arbor Hole Diameter Key Slit Width	Diameter D1 Thickness W2 Space Between Flange W1 Outer Diameter D2 Arbor Hole Diameter D3 Key Slit Width B

Feature	Measure	Symbol	Size (mm)
	Length	Ao	1.3
Cavity	Width	Во	1.7
Cavity	Depth	Ко	0.74
	Pitch	P1	4.0
Centerline	Cavity to Perforation (Length)	P2	2.0
Distance	Cavity to Perforation (Width)	Р3	3.5
Carrier Tape	Width	W	8.0

(Unless otherwise specified, all dimension tolerances per EIA-481)



### **Handling Precautions**

PARAMETER	RATING	STANDARD
ESD – Human Body Model (HBM)	Class 2	ESDA/JEDEC JS-001-2012
MSL – Moisture Sensitivity Level	Level 3	IPC/JEDEC J-STD-020



Caution!

ESD sensitive device

### **Solderability**

Compatible with both lead-free (260 °C max. reflow temperature) and tin/lead (245 °C max. reflow temperature) soldering processes.

Package lead plating: Electrolytic plated Au over Ni

### **RoHS Compliance**

This part is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free





### **Revision History**

Revision Code	Date	Comments
Α	6/30/2016	Initial Production Release
В	8/19/2016	Updated Functional Block Diagram
С	9/21/2016	Updated Performance Data
D	10/20/2016	Fixed Typo in CDM ESD Rating
F	2/17/2017	Updated Isolations
Н	5/25/2017	Fixed Typo in Isolation States; updated Pin locations on functional block diagram
I	6/07/2017	Updated Timing Diagram
J	7/18/2018	Updated PCB part number
K	4/03/2019	Updated Timing Diagram
L	6/25/2019	Fixed typo on Functional Block Diagram, added Branding Diagram and T&R info

#### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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